

## TABLE OF CONTENTS

Features .....	1
Applications .....	1
Functional Block Diagram .....	1
General Description .....	1
Revision History .....	2
Specifications .....	3
Absolute Maximum Ratings .....	5
ESD Caution.....	5
Pin Configuration and Function Descriptions .....	6
Typical Performance Characteristics.....	7
Downconverter Mode Using a Broadband Balun .....	7
Downconverter Mode Using a Johanson 2.5 GHz Balun.....	12
Downconverter Mode Using a Johanson 3.5 GHz Balun.....	15
Downconverter Mode Using a Johanson 5.5 GHz Balun.....	18
Spur Performance.....	21

## REVISION HISTORY

### 10/2020—Rev. B to Rev. C

Changes to Figure 1.....	1
Changes to Figure 2.....	6
Added Performance Up to 8 GHz Section and Table 5;	
Renumbered Sequentially .....	27
Updated Outline Dimensions.....	30
Changes to Ordering Guide.....	30

### 2/2015—Rev. A to Rev. B

Updated Outline Dimensions.....	29
Changes to Ordering Guide.....	29

### 6/2012—Rev. 0 to Rev. A

Changes to Downconverter Mode Using a Broadband Balun	
Section and Figure 6.....	7
Changes to Figure 11 .....	8
Changes to Figure 17, Figure 18, Figure 19, and Figure 20 .....	9
Changes to Figure 27 .....	11
Changed Downconverter Mode Using a Johanson 2.7 GHz	
Balun Section to Downconverter Mode Using a Johanson 2.5 GHz	
Balun Section .....	12

Performance Up to 8 GHz .....	<b>Error! Bookmark not defined.</b>
Circuit Description .....	24
LO Amplifier and Splitter .....	24
RF Voltage to Current (V-to-I) Converter.....	24
Mixer Cores.....	24
Mixer Load .....	24
Bias Circuit.....	24
Applications Information .....	25
Basic Connections.....	25
RF and LO Ports.....	25
IF Port.....	26
Performance Up to 8 GHz .....	27
Evaluation Board.....	28
Outline Dimensions.....	30
Ordering Guide .....	30

Changes to Downconverter Mode Using a Johanson 2.5 GHz	
Balun Section and Figure 31 .....	12
Changes o Figure 35 and Figure 36 .....	13
Changes to Figure 40 .....	14
Changes to Downconverter Mode Using a Johanson 3.5 GHz	
Balun Section and Figure 44 .....	15
Changes to Figure 48 and Figure 49 .....	16
Changes to Figure 53 .....	17
Changed Downconverter Mode Using a Johanson 5.7 GHz	
Balun Section to Downconverter Mode Using a Johanson 5.5 GHz	
Balun Section .....	18
Changes to Downconverter Mode Using a Johanson 5.5 GHz	
Balun Section .....	18
Changes to Figure 61 and Figure 62 .....	19
Changes to Figure 20 .....	20
Changes to 900 MHz Performance Section and 2090 MHz	
Performance Section.....	21
Changes to 2600 MHz Performance Section and 3500MHz	
Performance Section.....	22
Changes to 5800 MHz Performance Section.....	23
Updated Outline Dimensions .....	29

### 11/2009—Revision 0: Initial Version

## SPECIFICATIONS

$V_S = 5\text{ V}$ ,  $V_{SET} = 4\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = (f_{RF} - 153)\text{ MHz}$ , LO power = 0 dBm,  $Z_o^1 = 50\ \Omega$ , unless otherwise noted.

Table 1.

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
RF INPUT INTERFACE					
Return Loss	Tunable to >20 dB over a limited bandwidth		18		dB
Input Impedance			50		$\Omega$
RF Frequency Range		100		6000	MHz
OUTPUT INTERFACE					
Output Impedance	Differential impedance, $f = 200\text{ MHz}$		240		$\Omega$
IF Frequency Range	Can be matched externally to 3000 MHz	LF		600	MHz
DC Bias Voltage <sup>2</sup>	Externally generated	4.75	$V_S$	5.25	V
LO INTERFACE					
LO Power		-10	0	+10	dBm
Return Loss			18		dB
Input Impedance			50		$\Omega$
LO Frequency Range		100		6000	MHz
POWER INTERFACE					
Supply Voltage	Resistor programmable	4.75	5	5.25	V
Quiescent Current			220	300	mA
Disable Current			170		mA
Enable Time			182		ns
Disable Time			28		ns
DYNAMIC PERFORMANCE at $f_{RF} = 900\text{ MHz}/1900\text{ MHz}$					
Power Conversion Gain <sup>3</sup>	$f_{RF} = 900\text{ MHz}$		1.5		dB
	$f_{RF} = 1900\text{ MHz}$		1.6		dB
Voltage Conversion Gain <sup>4</sup>	$f_{RF} = 900\text{ MHz}$		7.5		dB
	$f_{RF} = 1900\text{ MHz}$		7.6		dB
SSB Noise Figure	$f_{CENT} = 900\text{ MHz}$		10		dB
	$f_{CENT} = 1900\text{ MHz}$		11		dB
SSB Noise Figure Under Blocking <sup>5</sup>	$f_{CENT} = 900\text{ MHz}$		18		dB
	$f_{CENT} = 1900\text{ MHz}$		22		dB
Input Third Order Intercept <sup>6</sup>	$f_{CENT} = 890\text{ MHz}$		26		dBm
	$f_{CENT} = 1890\text{ MHz}$		28		dBm
Input Second Order Intercept <sup>7</sup>	$f_{CENT} = 890\text{ MHz}$		60		dBm
	$f_{CENT} = 1890\text{ MHz}$		45		dBm
Input 1 dB Compression Point	$f_{RF} = 900\text{ MHz}$		12		dBm
	$f_{RF} = 1900\text{ MHz}$		12		dBm
LO to IF Output Leakage	Unfiltered IF output		-35		dBm
LO to RF Input Leakage			-30		dBm
RF to IF Output Isolation			25		dBc
RFI1 to RFI2 Channel Isolation			45		dBc
IF/2 Spurious <sup>8</sup>	0 dBm input power, $f_{RF} = 900\text{ MHz}$		-68		dBc
IF/3 Spurious <sup>8</sup>	0 dBm input power, $f_{RF} = 900\text{ MHz}$		-67		dBc
IF/2 Spurious <sup>8</sup>	0 dBm input power, $f_{RF} = 1900\text{ MHz}$		-53		dBc
IF/3 Spurious <sup>8</sup>	0 dBm input power, $f_{RF} = 1900\text{ MHz}$		-59		dBc
DYNAMIC PERFORMANCE at $f_{RF} = 2500\text{ MHz}$ <sup>9</sup>					
Power Conversion Gain <sup>10</sup>	$f_{CENT} = 2145\text{ MHz}$		-0.5		dB
Voltage Conversion Gain <sup>4</sup>			5.67		dB
SSB Noise Figure			11.5		dB
SSB Noise Figure Under Blocking <sup>11</sup>			18		dB
Input Third Order Intercept <sup>6</sup>			30		dBm

Parameter	Test Conditions/Comments	Min	Typ	Max	Unit
Input Second Order Intercept <sup>7</sup>	$f_{\text{CENT}} = 2500 \text{ MHz}$		47		dBm
Input 1 dB Compression Point			13		dBm
LO to IF Output Leakage	Unfiltered IF output		36		dBm
LO to RF Input Leakage			31		dBm
RF to IF Output Isolation			26		dBc
RF1 to RF12 Channel Isolation			42		dBc
IF/2 Spurious <sup>8</sup>	0 dBm input power		-52		dBc
IF/3 Spurious <sup>8</sup>	0 dBm input power		-56		dBc
DYNAMIC PERFORMANCE at $f_{\text{RF}} = 3500 \text{ MHz}$ <sup>12</sup>					
Power Conversion Gain <sup>13</sup>			-0.5		dB
Voltage Conversion Gain <sup>4</sup>			5.5		dB
SSB Noise Figure			12.5		dB
SSB Noise Figure Under Blocking <sup>14</sup>	$f_{\text{CENT}} = 3500 \text{ MHz}$		18		dB
Input Third Order Intercept <sup>5</sup>	$f_{\text{CENT}} = 3500 \text{ MHz}$		25		dBm
Input Second Order Intercept <sup>7</sup>	$f_{\text{CENT}} = 3500 \text{ MHz}$		39		dBm
Input 1 dB Compression Point			13		dBm
LO to IF Output Leakage	Unfiltered IF output		33		dBm
LO to RF Input Leakage			28		dBm
RF to IF Output Isolation			31		dBc
RF1 to RF12 Channel Isolation			39		dBc
IF/2 Spurious <sup>8</sup>	0 dBm input power		-46		dBc
IF/3 Spurious <sup>8</sup>	0 dBm input power		-63		dBc
DYNAMIC PERFORMANCE at $f_{\text{RF}} = 5500 \text{ MHz}$ <sup>15</sup>					
Power Conversion Gain <sup>16</sup>			-3		dB
Voltage Conversion Gain <sup>4</sup>			5.67		dB
SSB Noise Figure			14		dB
SSB Noise Figure Under Blocking <sup>17</sup>	$f_{\text{CENT}} = 5800 \text{ MHz}$		17		dB
Input Third Order Intercept <sup>5</sup>	$f_{\text{CENT}} = 5500 \text{ MHz}$		23		dBm
Input Second Order Intercept <sup>7</sup>	$f_{\text{CENT}} = 5500 \text{ MHz}$		35		dBm
Input 1 dB Compression Point			13		dBm
LO to IF Output Leakage	Unfiltered IF output		42		dBm
LO to RF Input Leakage			27		dBm
RF to IF Output Isolation			50		dBc
RF1 to RF12 Channel Isolation			33		dBc
IF/2 Spurious <sup>8</sup>	0 dBm input power		-49		dBc
IF/3 Spurious <sup>8</sup>	0 dBm input power		-64		dBc

<sup>1</sup>  $Z_0$  is the characteristic impedance assumed for all measurements and the PCB.

<sup>2</sup> Supply voltage must be applied from an external circuit through choke inductors.

<sup>3</sup> Excluding 4:1 IF port transformer (TC4-1W+), RF and LO port transformers (TC1-1-13M+), and PCB loss.

<sup>4</sup>  $Z_{\text{SOURCE}} = 50 \Omega$ , differential;  $Z_{\text{LOAD}} = 200 \Omega$ , differential 5 dBm;  $Z_{\text{SOURCE}}$  is the impedance of the source instrument;  $Z_{\text{LOAD}}$  is the load impedance at the output.

<sup>5</sup>  $f_{\text{RF1}} = f_{\text{CENT}}$ ,  $f_{\text{BLOCKER}} = (f_{\text{CENT}} - 5) \text{ MHz}$ ,  $f_{\text{LO}} = (f_{\text{CENT}} - 153) \text{ MHz}$ , blocker level = 0 dBm.

<sup>6</sup>  $f_{\text{RF1}} = (f_{\text{CENT}} - 1) \text{ MHz}$ ,  $f_{\text{RF2}} = f_{\text{CENT}}$ ,  $f_{\text{LO}} = (f_{\text{CENT}} - 153) \text{ MHz}$ , each RF tone at -10 dBm.

<sup>7</sup>  $f_{\text{RF1}} = f_{\text{CENT}}$ ,  $f_{\text{RF2}} = (f_{\text{CENT}} + 100) \text{ MHz}$ ,  $f_{\text{LO}} = (f_{\text{CENT}} - 153) \text{ MHz}$ , each RF tone at -10 dBm.

<sup>8</sup> For details, see the Spur Performance section.

<sup>9</sup>  $V_S = 5 \text{ V}$ ,  $V_{\text{SET}} = 4.5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{\text{LO}} = (f_{\text{RF}} - 211) \text{ MHz}$ , LO power = 0 dBm,  $Z_0 = 50 \Omega$ .

<sup>10</sup> Excluding 4:1 IF port transformer (TC4-1W+), RF and LO port transformers (2500BL14M050), and PCB loss.

<sup>11</sup>  $f_{\text{RF1}} = f_{\text{CENT}}$ ,  $f_{\text{BLOCKER}} = (f_{\text{CENT}} - 5) \text{ MHz}$ ,  $f_{\text{LO}} = (f_{\text{CENT}} - 235) \text{ MHz}$ , blocker level = 0 dBm.

<sup>12</sup>  $V_S = 5 \text{ V}$ ,  $V_{\text{SET}} = 5 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{\text{LO}} = (f_{\text{RF}} - 153) \text{ MHz}$ , LO power = 0 dBm,  $Z_0 = 50 \Omega$ .

<sup>13</sup> Including 4:1 IF port transformer (TC4-1W+), RF and LO port transformers (3600BL14M050), and PCB loss.

<sup>14</sup>  $f_{\text{RF1}} = f_{\text{CENT}}$ ,  $f_{\text{BLOCKER}} = (f_{\text{CENT}} - 5) \text{ MHz}$ ,  $f_{\text{LO}} = (f_{\text{CENT}} - 153) \text{ MHz}$ , blocker level = -20 dBm.

<sup>15</sup>  $V_S = 5 \text{ V}$ ,  $V_{\text{SET}} = 4.8 \text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $f_{\text{LO}} = (f_{\text{RF}} - 380) \text{ MHz}$ , LO power = 0 dBm,  $Z_0 = 50 \Omega$ .

<sup>16</sup> Including 4:1 IF port transformer (TC4-1W+), RF and LO port transformers (5400BL15B050), and PCB loss.

<sup>17</sup>  $f_{\text{RF1}} = f_{\text{CENT}}$ ,  $f_{\text{BLOCKER}} = (f_{\text{CENT}} - 5) \text{ MHz}$ ,  $f_{\text{LO}} = (f_{\text{CENT}} - 300) \text{ MHz}$ , blocker level = -20 dBm.

## ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage, VPOS	5.5 V
VSET, ENBL	5.5 V
OP1+, OP1–, OP2+, OP2–	5.5 V
RF Input Power	20 dBm
Internal Power Dissipation	1.6 W
$\theta_{JA}$ (Exposed Paddle Soldered Down) <sup>1</sup>	26.5°C/W
$\theta_{JC}$ (at Exposed Paddle)	8.7°C/W
Maximum Junction Temperature	150°C
Operating Temperature Range	–40°C to +85°C
Storage Temperature Range	–65°C to +150°C

<sup>1</sup> As measured on the evaluation board. For details, see the Evaluation Board section.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

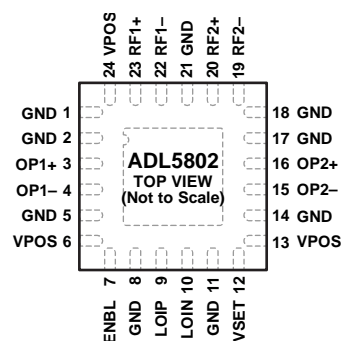
### ESD CAUTION



#### ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



**NOTES**  
1. EXPOSED PADDLE. MUST BE SOLDERED TO GROUND.

07882-002

Figure 2. Pin Configuration

Table 3. Pin Function Descriptions

Pin No.	Mnemonic	Function
1, 2, 5, 8, 11, 14, 17, 18, 21	GND	Device Common (DC Ground).
3, 4	OP1+, OP1–	Channel 1 Mixer Differential Output Terminals. Bias must be applied through pull-up choke inductors or the center tap of the IF transformer.
6, 13, 24	VPOS	Positive Supply Voltage. 5.0 V nominal.
7	ENBL	Device Enable. Pull low or leave disconnected to enable the device; pull high to disable the device.
9, 10	LOIP, LOIN	Differential LO Input Terminals. Internally matched to 50 $\Omega$ ; must be ac-coupled.
12	VSET	High Input IP3 Bias Control. For high input IP3 performance, apply ~4 V to 5 V. Improved noise figure (NF) performance and lower supply current can be set by applying ~2 V to 3 V to the VSET pin. A resistor can be connected to the supply to raise the voltage, whereas a resistor to GND lowers the voltage.
15, 16	OP2–, OP2+	Channel 2 Mixer Differential Output Terminals. Bias must be applied through pull-up choke inductors or the center tap of the IF transformer.
19, 20	RF2–, RF2+	Differential RF Input Terminals for Channel 2. Internally matched to 50 $\Omega$ ; must be ac-coupled.
22, 23	RF1–, RF1+	Differential RF Input Terminals for Channel 1. Internally matched to 50 $\Omega$ ; must be ac-coupled.
	EPAD	Exposed Paddle. Must be soldered to ground.

## TYPICAL PERFORMANCE CHARACTERISTICS

### DOWNCONVERTER MODE USING A BROADBAND BALUN

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4\text{ V}$ ,  $I_F = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side local oscillator (LO), unless otherwise noted. Insertion loss of input and output baluns (TC1-1-13M+, TC4-1W+) is extracted from the gain measurement.

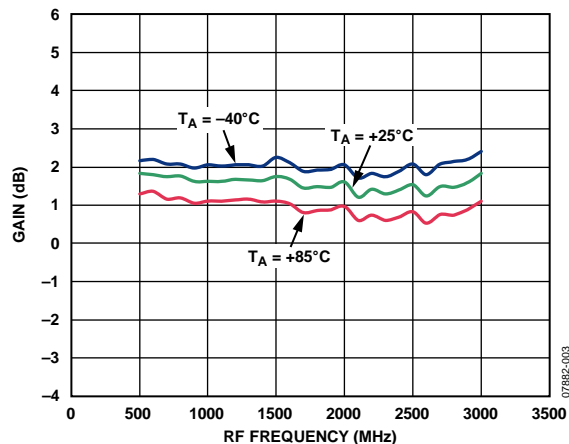


Figure 3. Power Conversion Gain vs. RF Frequency

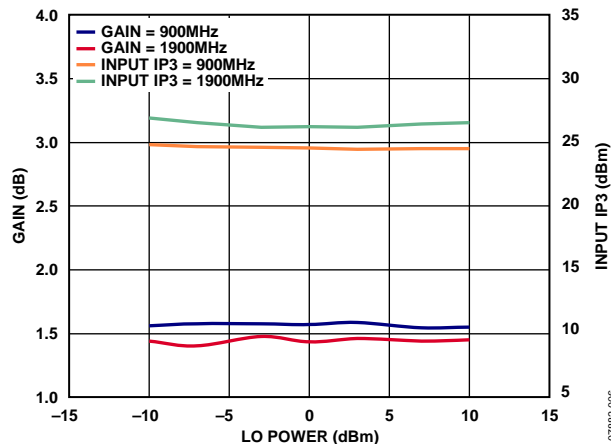


Figure 6. Power Conversion Gain and Input IP3 vs. LO Power

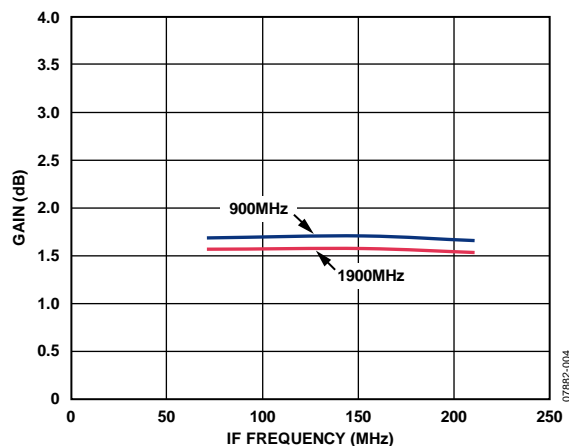


Figure 4. Power Conversion Gain vs. IF Frequency

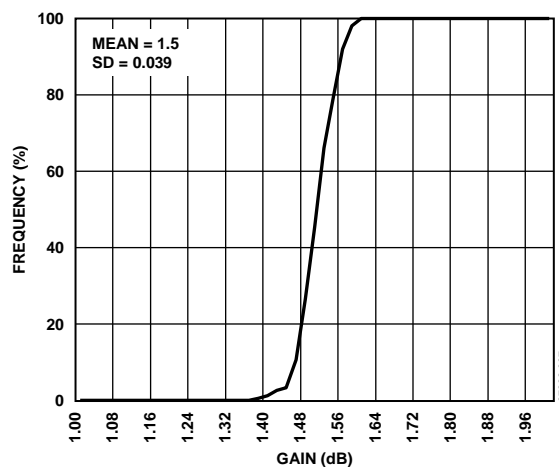


Figure 7. Power Conversion Gain Distribution

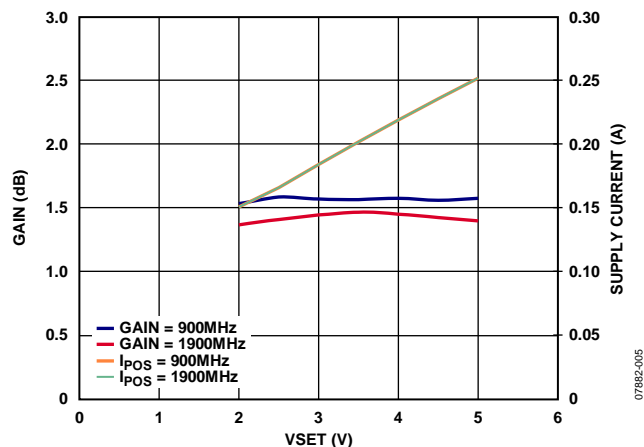


Figure 5. Power Conversion Gain and  $I_{POS}$  vs.  $V_{SET}$

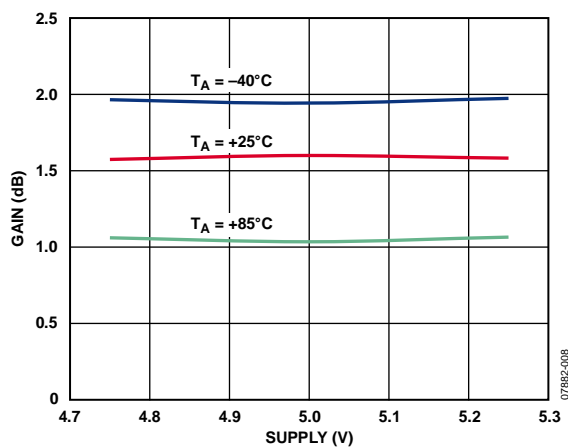


Figure 8. Power Conversion Gain vs. Supply Voltage

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side local oscillator (LO), unless otherwise noted. Insertion loss of input and output baluns (TC1-1-13M+, TC4-1W+) is extracted from the gain measurement.

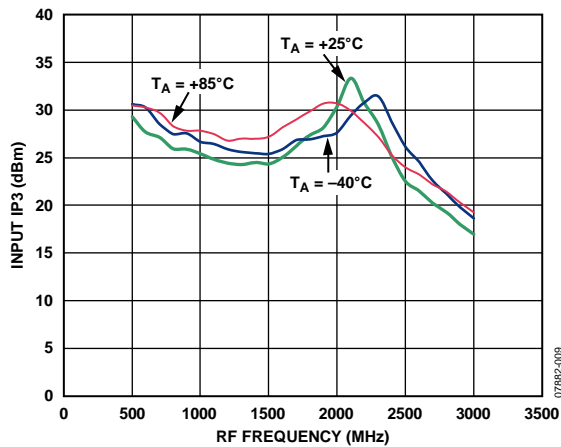


Figure 9. Input IP3 vs. RF Frequency

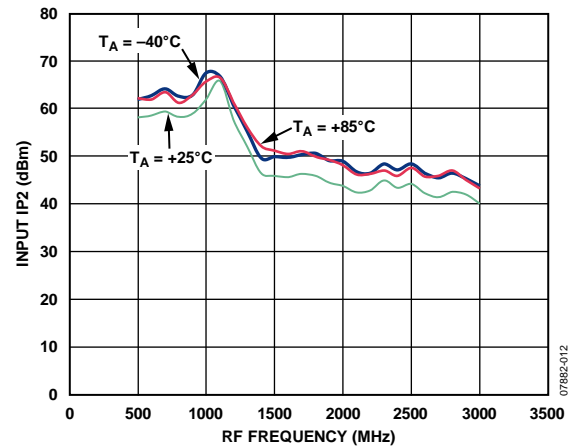


Figure 12. Input IP2 vs. RF Frequency

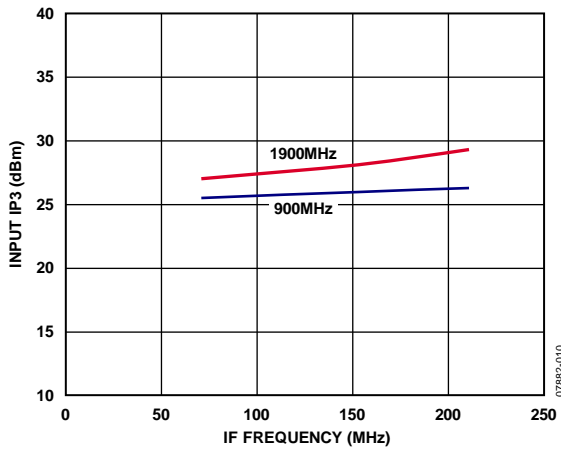


Figure 10. Input IP3 vs. IF Frequency

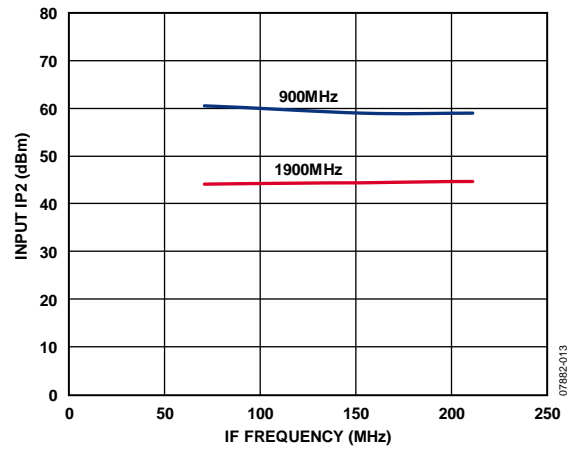


Figure 13. Input IP2 vs. IF Frequency

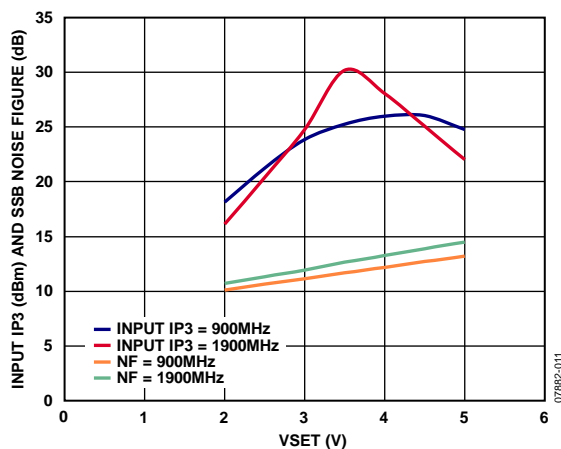


Figure 11. Input IP3, Noise Figure vs. VSET

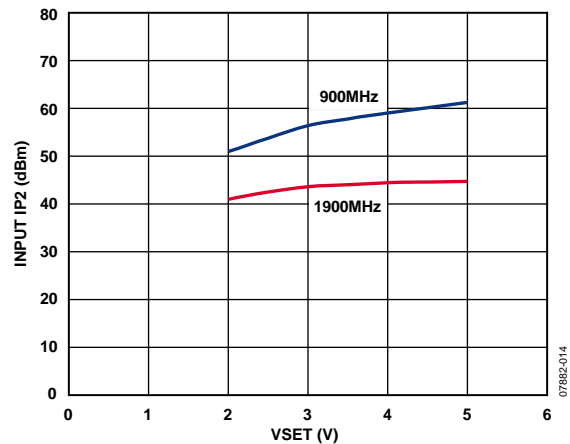


Figure 14. Input IP2 vs. VSET

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side local oscillator (LO), unless otherwise noted. Insertion loss of input and output baluns (TC1-1-13M+, TC4-1W+) is extracted from the gain measurement.

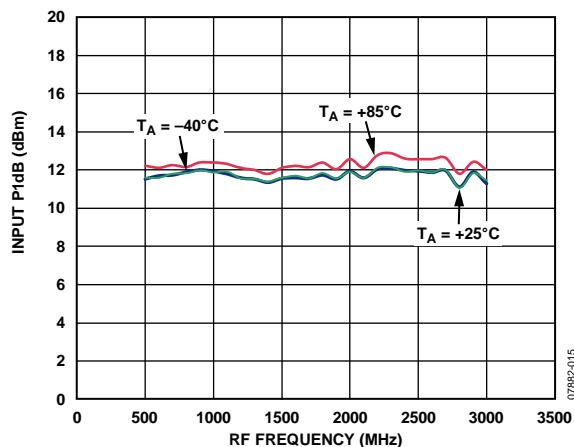


Figure 15. Input P1dB vs. RF Frequency

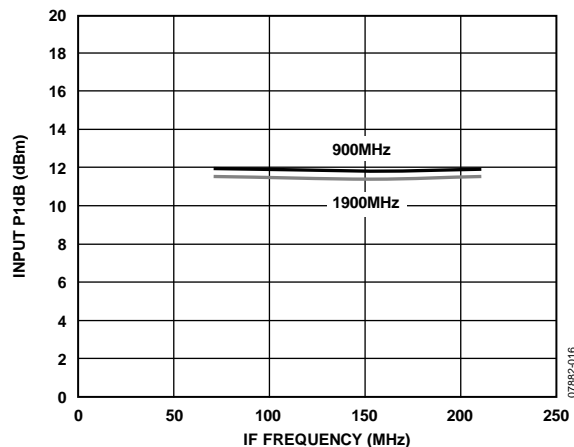


Figure 16. Input P1dB vs. IF Frequency

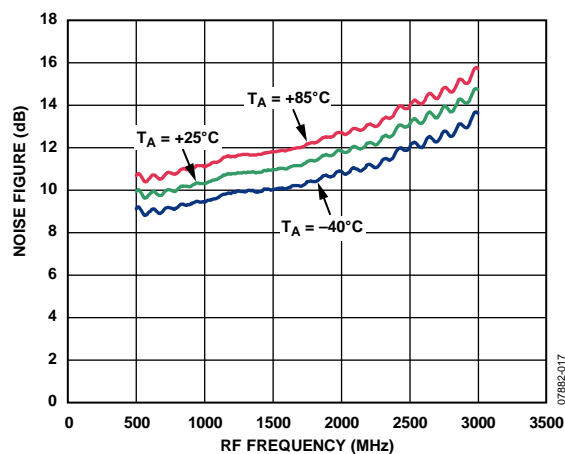


Figure 17. SSB Noise Figure vs. RF Frequency ( $V_{SET} = 2.0\text{ V}$ )

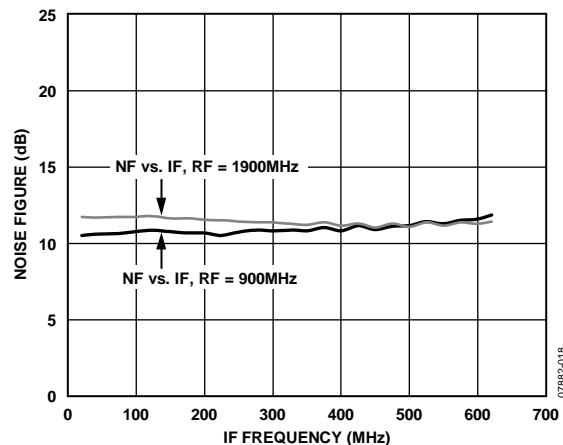


Figure 18. SSB Noise Figure vs. IF Frequency ( $V_{SET} = 2.0\text{ V}$ )

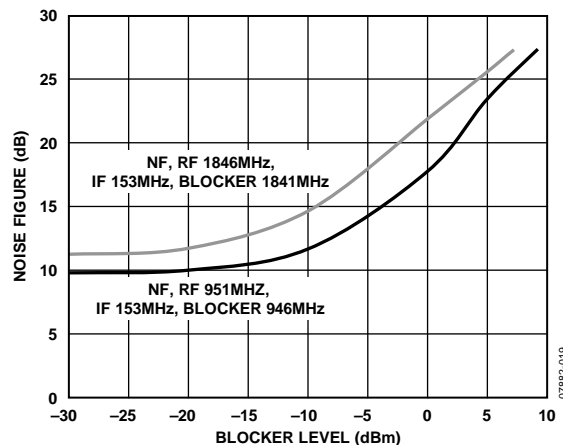


Figure 19. SSB Noise Figure vs. Blocker Level ( $V_{SET} = 2.0\text{ V}$ )

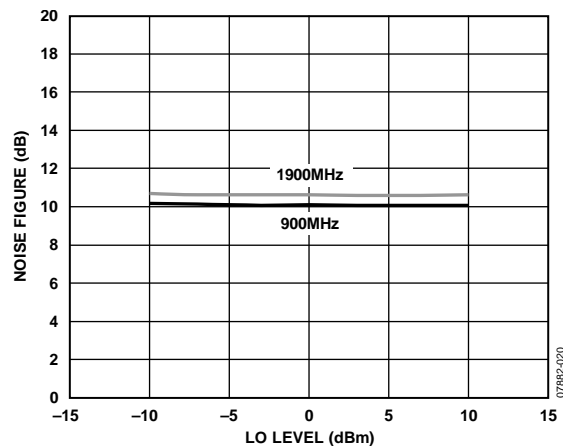


Figure 20. SSB Noise Figure vs. LO Drive ( $V_{SET} = 2.0\text{ V}$ )



$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side local oscillator (LO), unless otherwise noted. Insertion loss of input and output baluns (TC1-1-13M+, TC4-1W+) is extracted from the gain measurement.

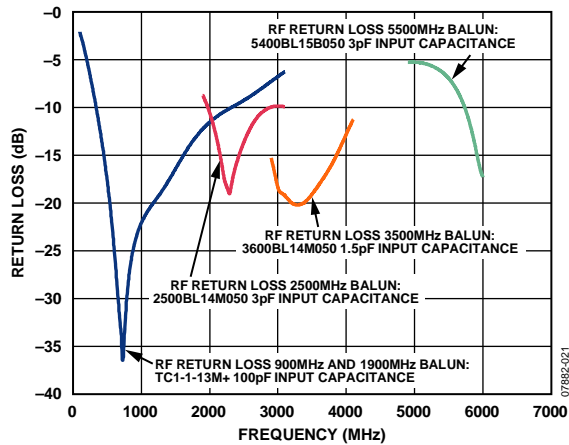


Figure 21. RF Return Loss Measured Differentially at the RF Port

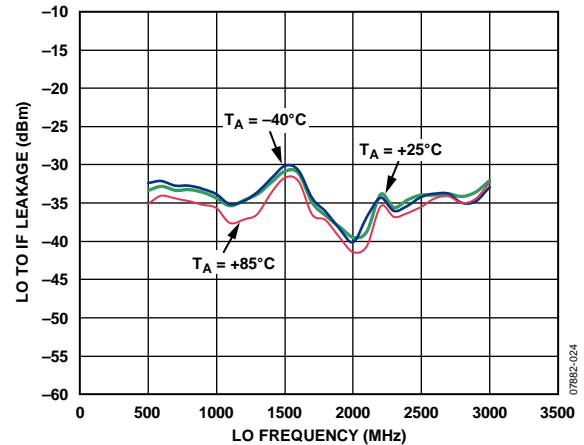


Figure 24. LO to IF Leakage vs. LO Frequency

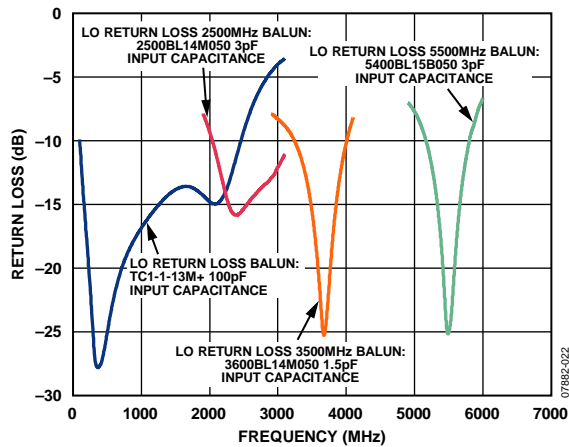


Figure 22. LO Return Loss Measured Differentially at the LO Port

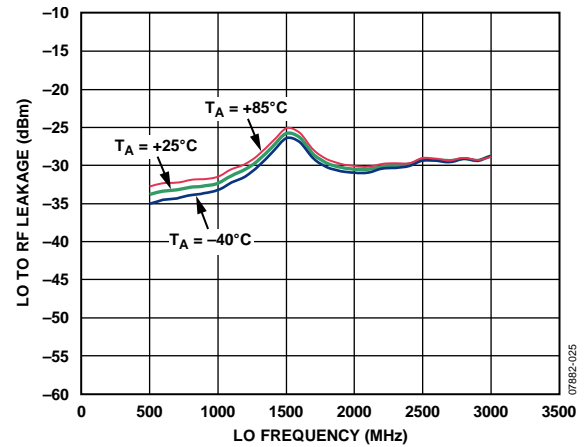


Figure 25. LO to RF Leakage vs. LO Frequency

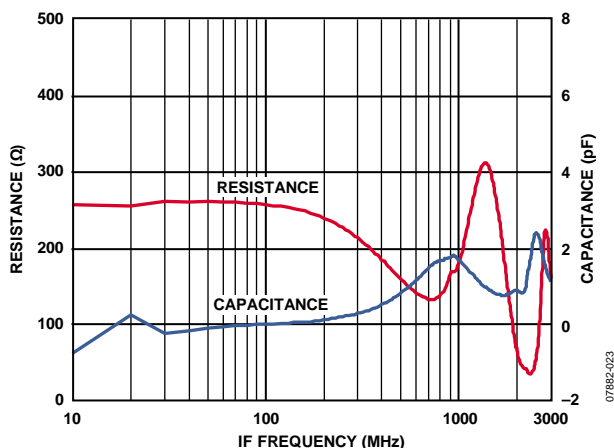


Figure 23. IF Differential Output Impedance (R Parallel C Equivalent)

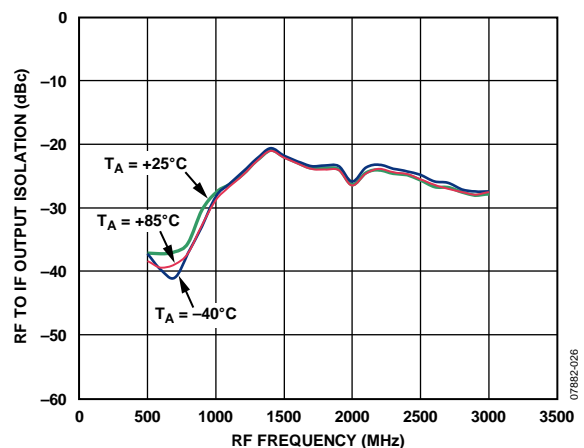


Figure 26. RF to IF Output Isolation vs. RF Frequency

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side local oscillator (LO), unless otherwise noted. Insertion loss of input and output baluns (TC1-1-13M+, TC4-1W+) is extracted from the gain measurement.

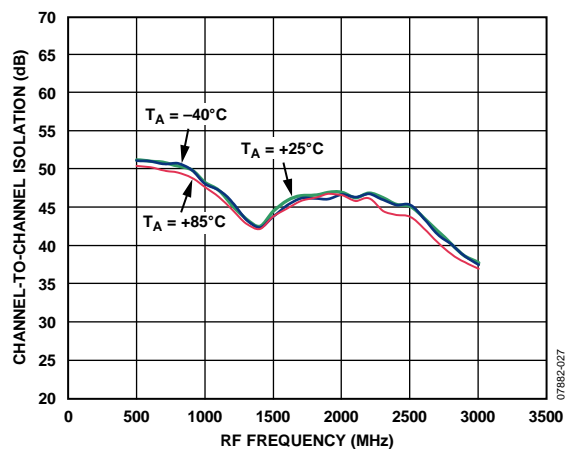


Figure 27. Channel-to-Channel Isolation

### DOWNCONVERTER MODE USING A JOHANSON 2.5 GHZ BALUN

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4.5\text{ V}$ ,  $I_F = 211\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (2500BL14M050, TC4-1W+) is included in the gain measurement.

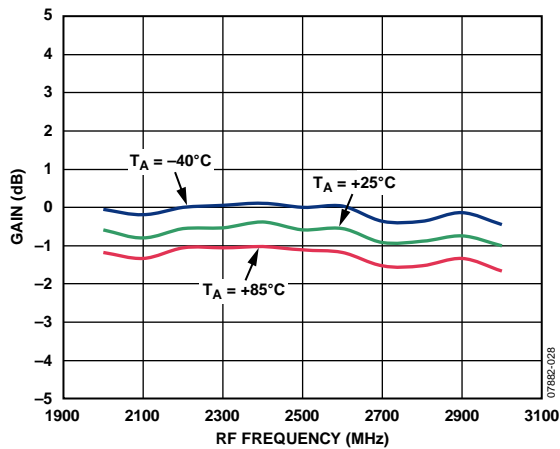


Figure 28. Power Conversion Gain vs. RF Frequency

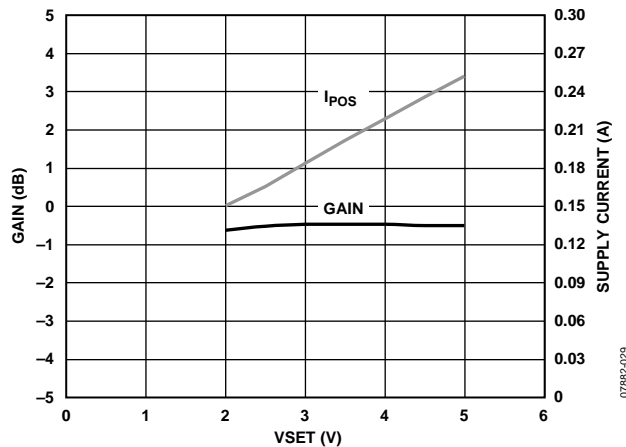


Figure 29. Power Conversion Gain and  $I_{POS}$  vs.  $V_{SET}$

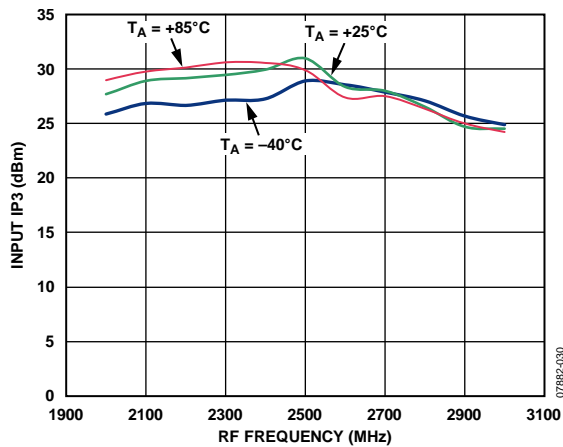


Figure 30. Input IP3 vs. RF Frequency

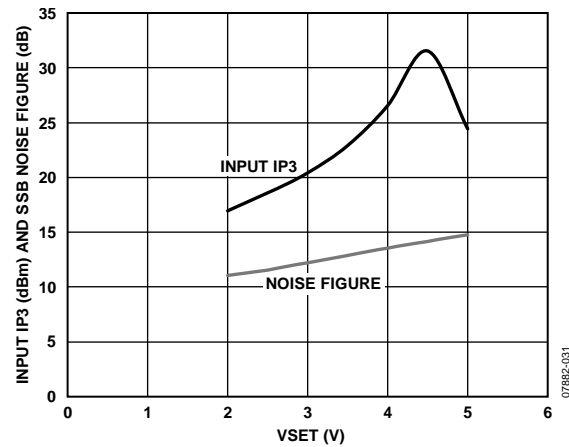


Figure 31. Input IP3, Noise Figure vs.  $V_{SET}$

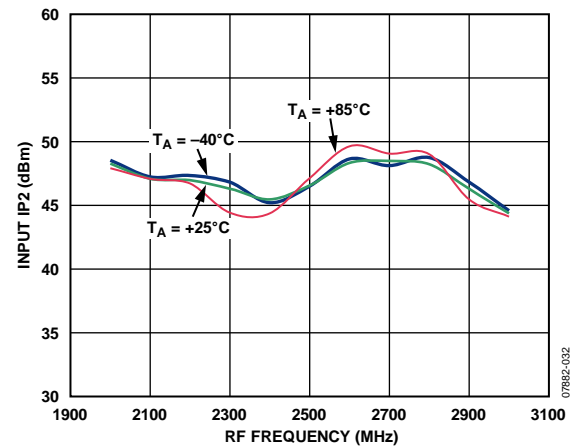


Figure 32. Input IP2 vs. RF Frequency

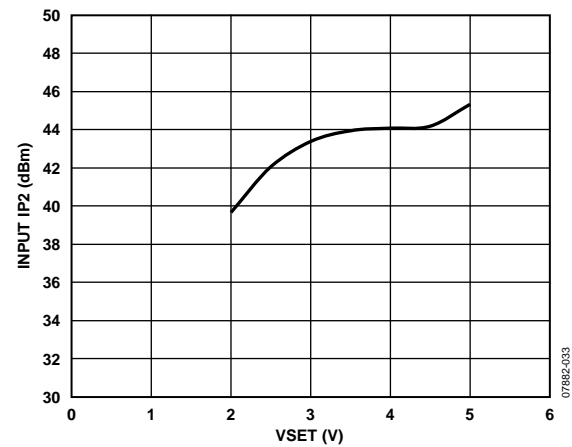


Figure 33. Input IP2 vs.  $V_{SET}$

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4.5\text{ V}$ ,  $IF = 211\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (2500BL14M050, TC4-1W+) is included in the gain measurement

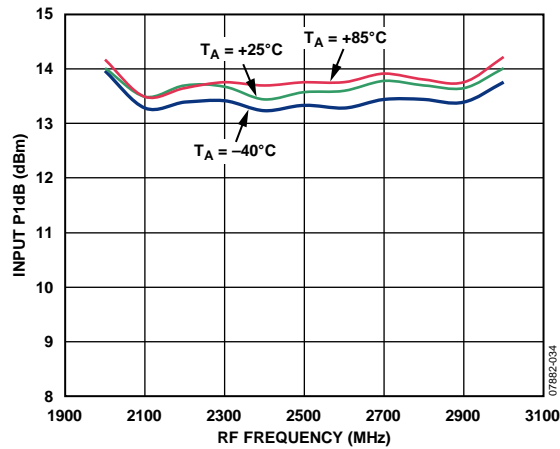


Figure 34. Input P1dB vs. RF Frequency

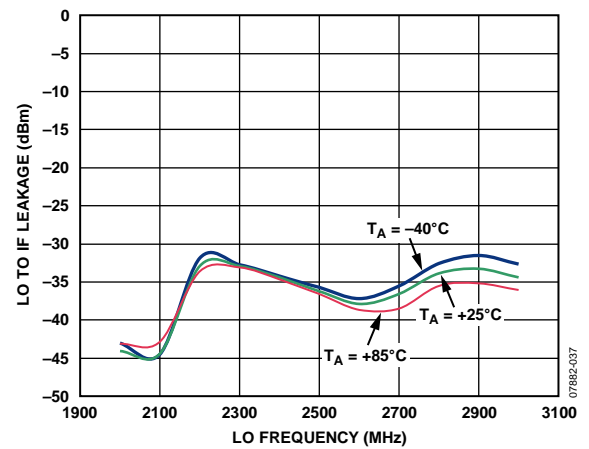


Figure 37. LO to IF Leakage vs. LO Frequency

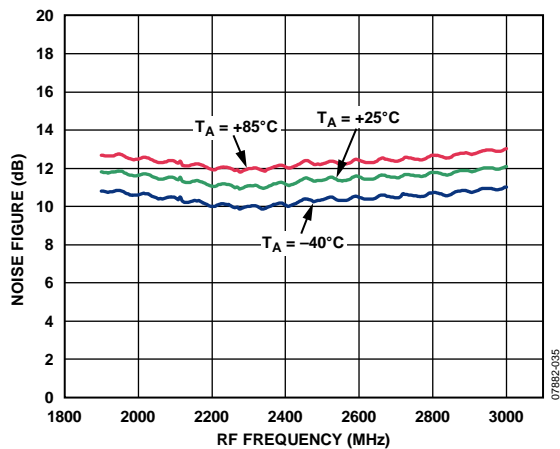


Figure 35. SSB Noise Figure vs. RF Frequency ( $V_{SET} = 2.0\text{ V}$ )

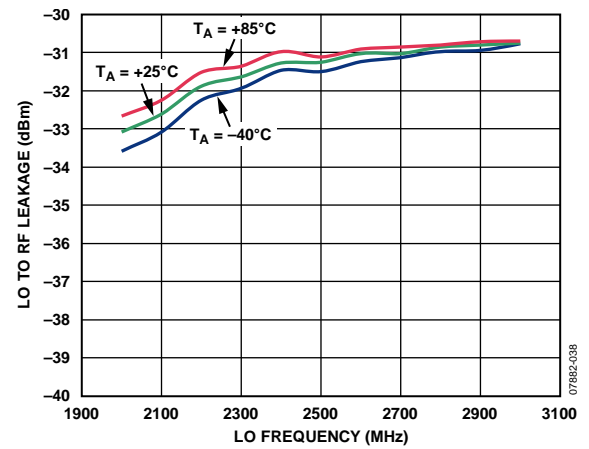


Figure 38. LO to RF Leakage vs. LO Frequency

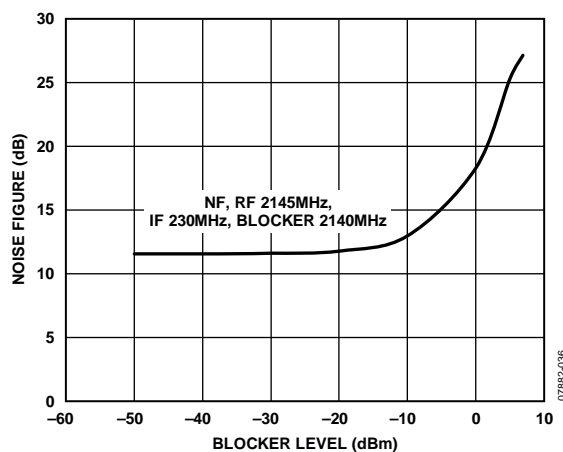


Figure 36. SSB Noise Figure vs. Blocker Level ( $V_{SET} = 2.0\text{ V}$ )

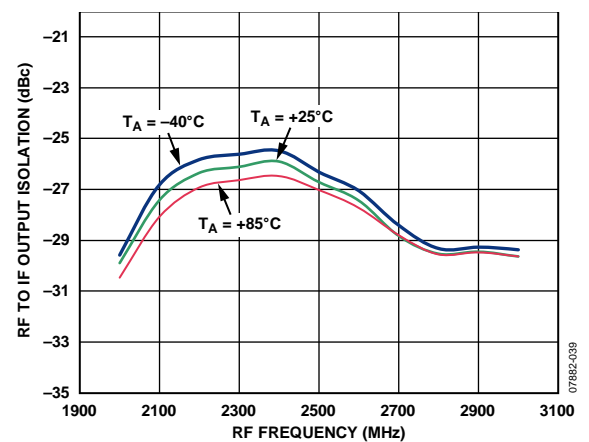


Figure 39. RF to IF Output Isolation vs. RF Frequency

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4.5\text{ V}$ ,  $IF = 211\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (2500BL14M050, TC4-1W+) is included in the gain measurement

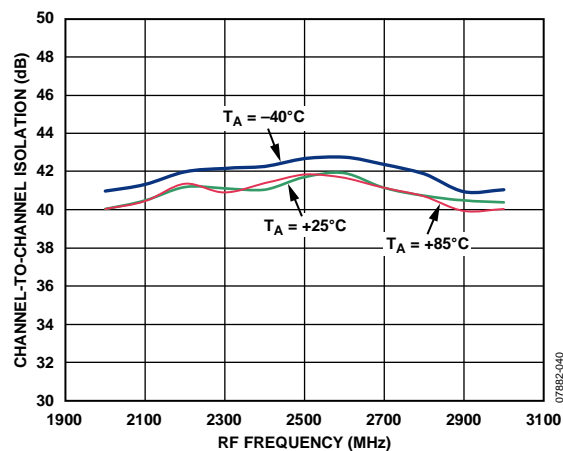


Figure 40. Channel-to-Channel Isolation

### DOWNCONVERTER MODE USING A JOHANSON 3.5 GHz BALUN

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 5\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (3600BL14M050, TC4-1W+) is included in the gain measurement.

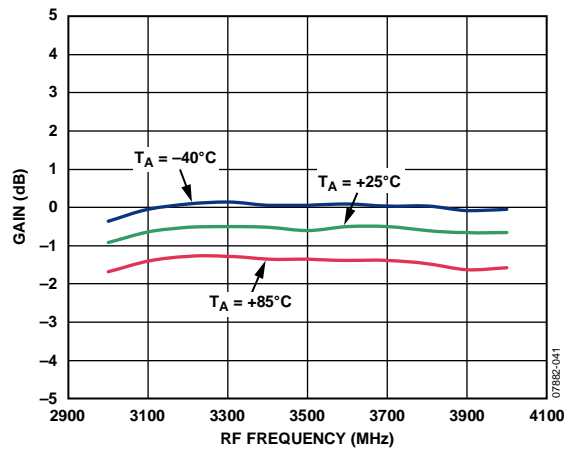


Figure 41. Power Conversion Gain vs. RF Frequency

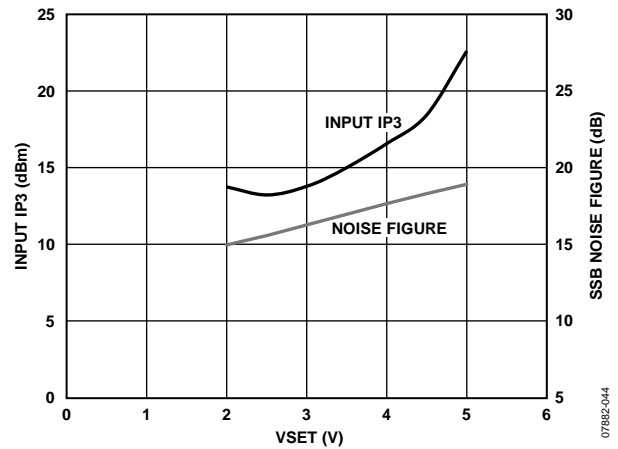


Figure 44. Input IP3, Noise Figure vs. VSET

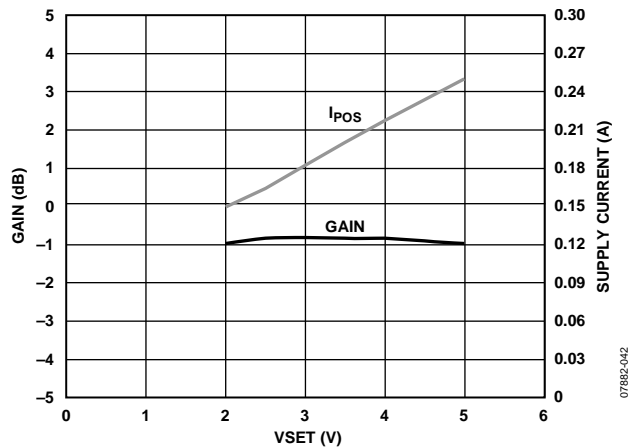


Figure 42. Power Conversion Gain and  $I_{POS}$  vs. VSET

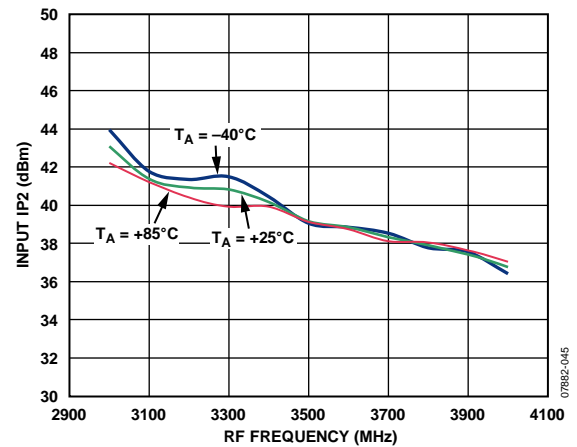


Figure 45. Input IP2 vs. RF Frequency

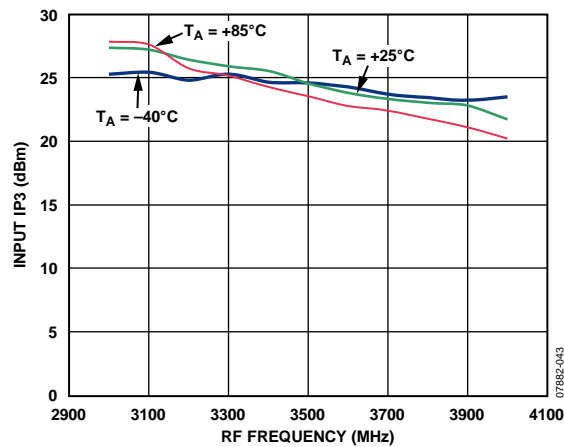


Figure 43. Input IP3 vs. RF Frequency

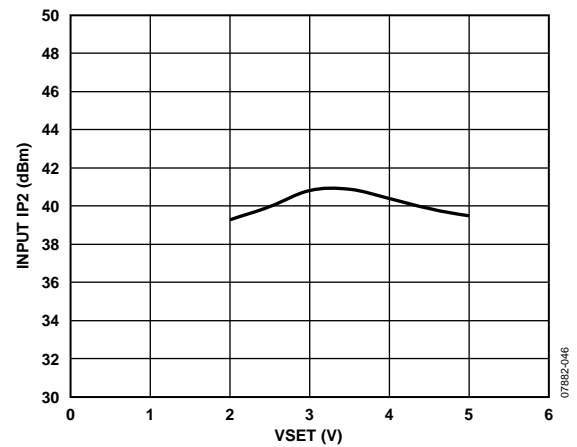


Figure 46. Input IP2 vs. VSET

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 5\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (3600BL14M050, TC4-1W+) is included in the gain measurement.

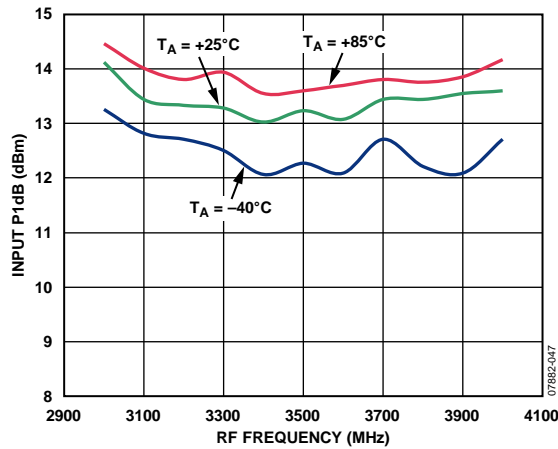


Figure 47. Input P1dB vs. RF Frequency

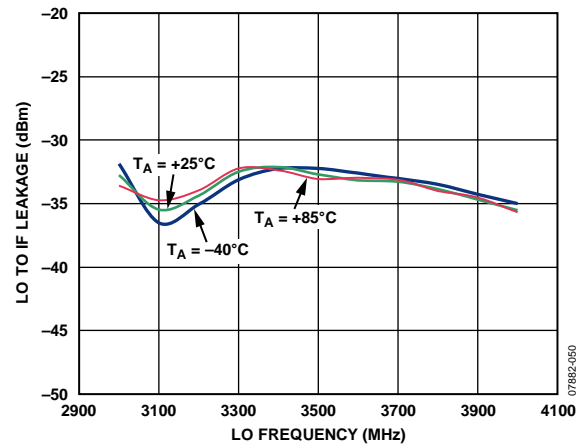


Figure 50. LO to IF Leakage vs. LO Frequency

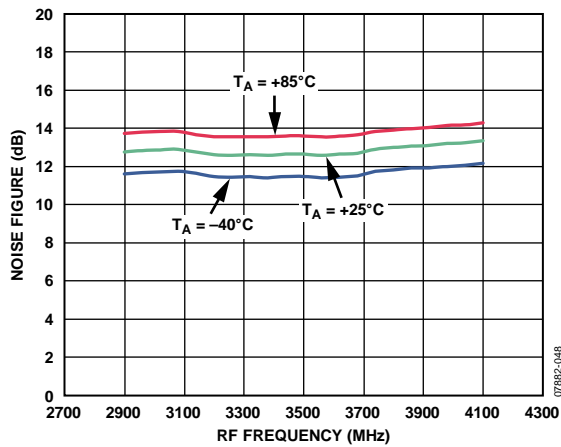


Figure 48. SSB Noise Figure vs. RF Frequency ( $V_{SET} = 2.0\text{ V}$ )

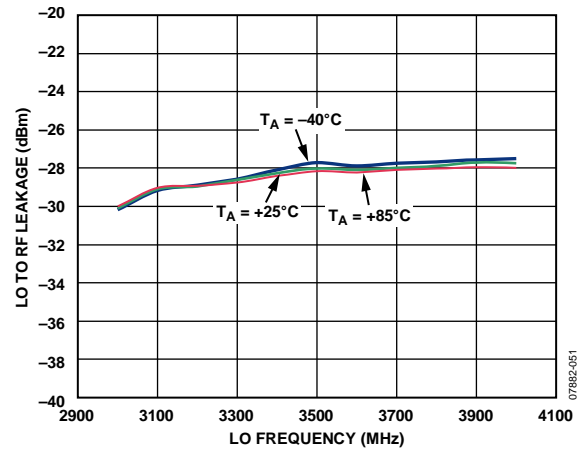


Figure 51. LO to RF Leakage vs. LO Frequency

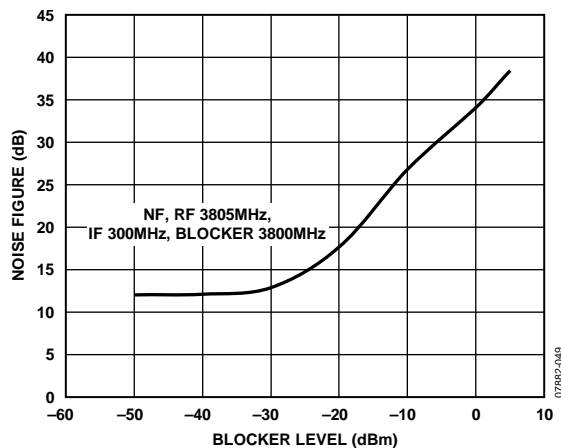


Figure 49. SSB Noise Figure vs. Blocker Level ( $V_{SET} = 2.0\text{ V}$ )

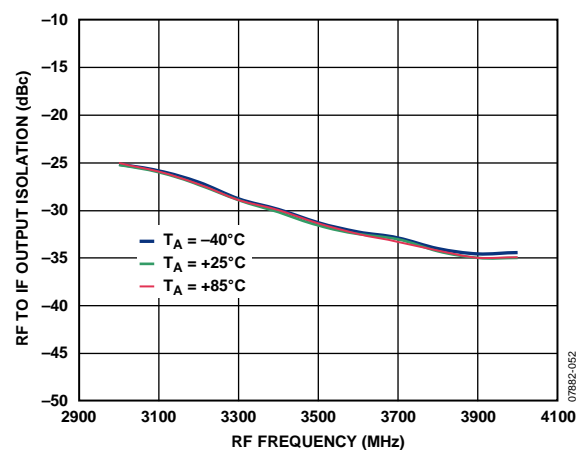


Figure 52. RF to IF Output Isolation vs. RF Frequency

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 5\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (3600BL14M050, TC4-1W+) is included in the gain measurement.

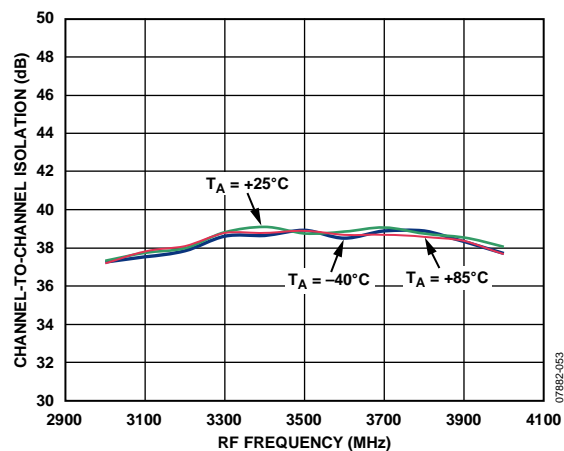


Figure 53. Channel-to-Channel Isolation



### DOWNCONVERTER MODE USING A JOHANSON 5.5 GHZ BALUN

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 4.8\text{ V}$ ,  $f_F = 380\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (5400BL15B050, TC4-1W+) is included in the gain measurement.

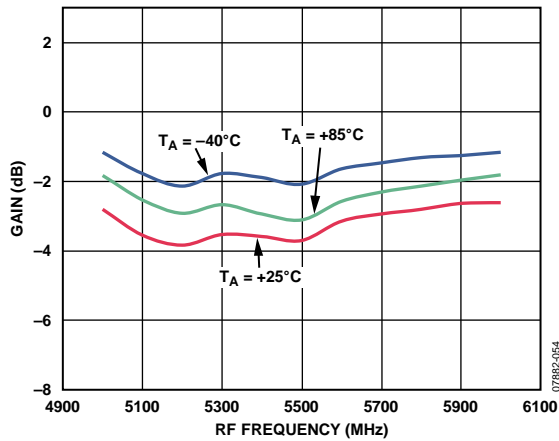


Figure 54. Power Conversion Gain vs. RF Frequency

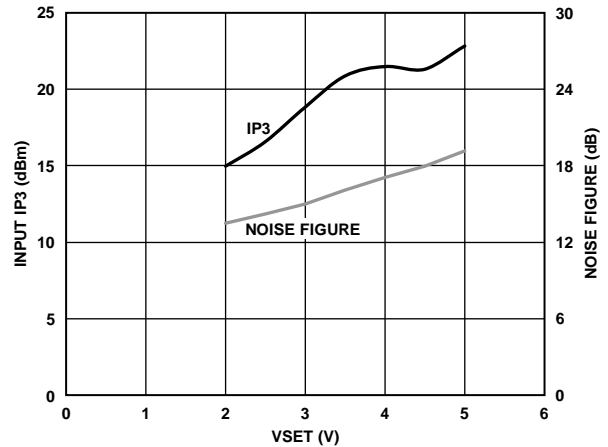


Figure 57. Input IP3, Noise Figure vs. VSET

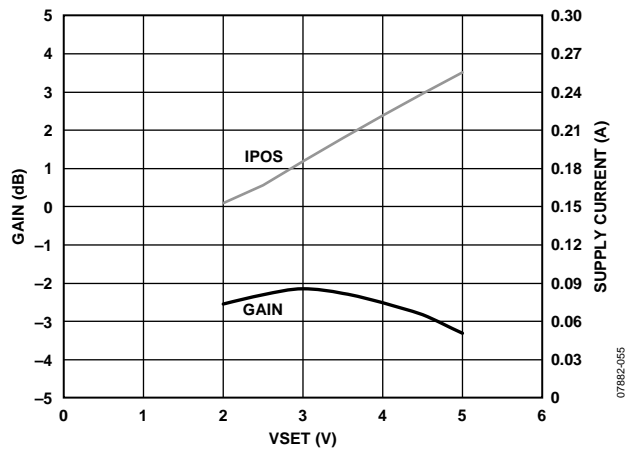


Figure 55. Power Conversion Gain and  $I_{POS}$  vs. VSET

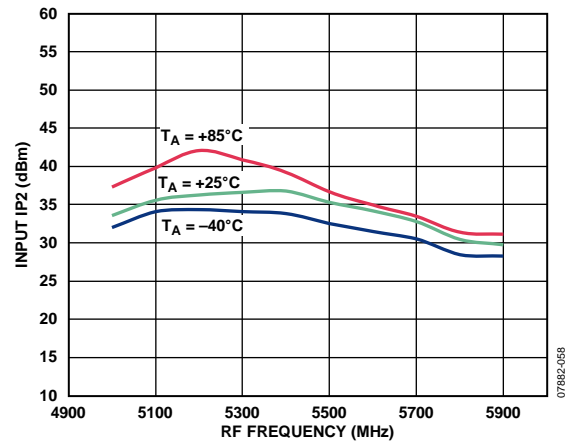


Figure 58. Input IP2 vs. RF Frequency

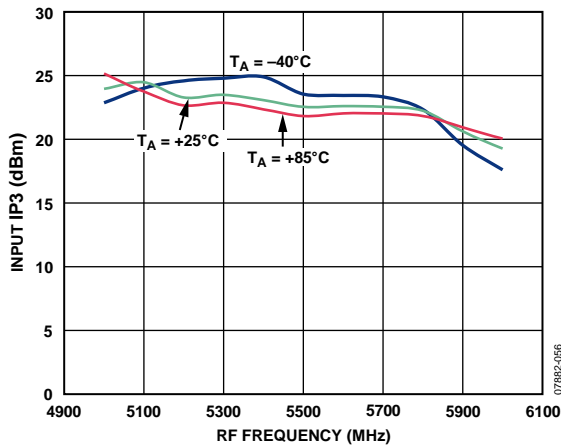


Figure 56. Input IP3 vs. RF Frequency

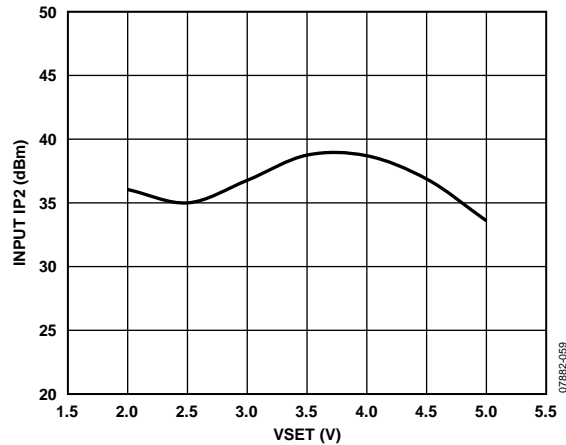


Figure 59. Input IP2 vs. VSET

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 5\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (3600BL14M050, TC4-1W+) is included in the gain measurement.

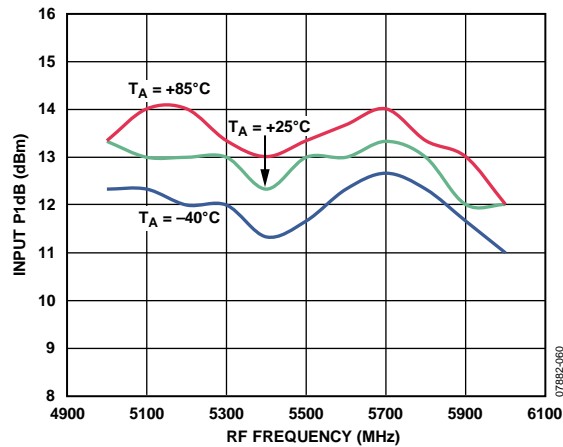


Figure 60. Input P1dB vs. RF Frequency

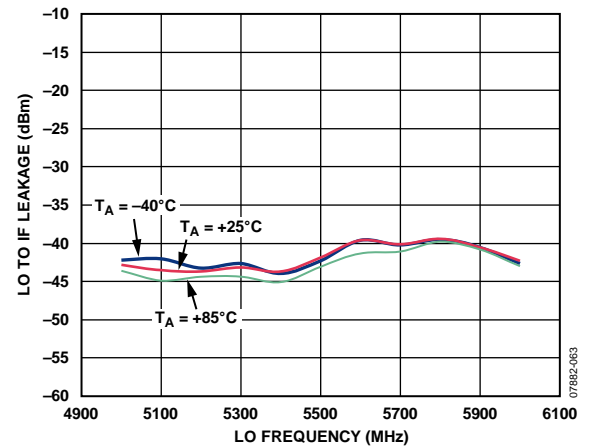


Figure 63. LO to IF Leakage vs. LO Frequency

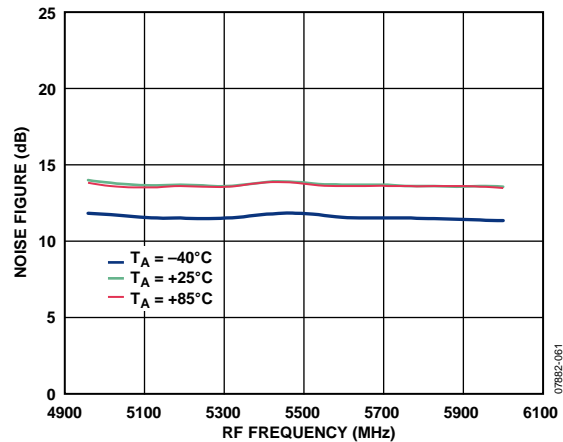


Figure 61. SSB Noise Figure vs. RF Frequency ( $V_{SET} = 2.0\text{ V}$ )

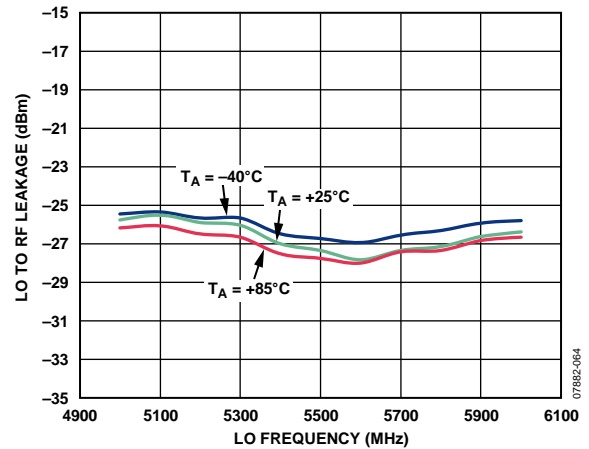


Figure 64. LO to RF Leakage vs. LO Frequency

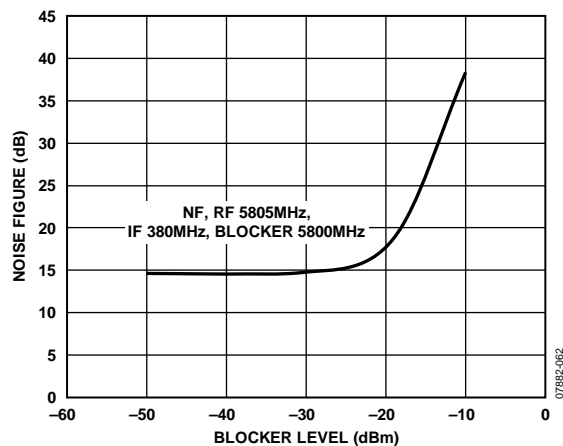


Figure 62. SSB Noise Figure vs. Blocker Level ( $V_{SET} = 2.0\text{ V}$ )

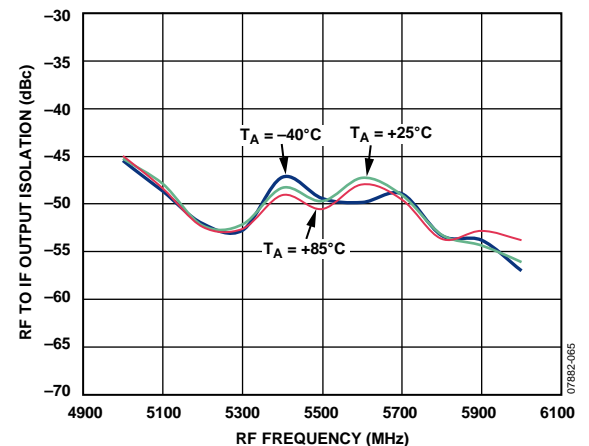


Figure 65. RF to IF Output Isolation vs. RF Frequency

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{SET} = 5\text{ V}$ ,  $IF = 153\text{ MHz}$ , as measured using a typical circuit schematic with low-side LO, unless otherwise noted. Insertion loss of input and output baluns (3600BL14M050, TC4-1W+) is included in the gain measurement.

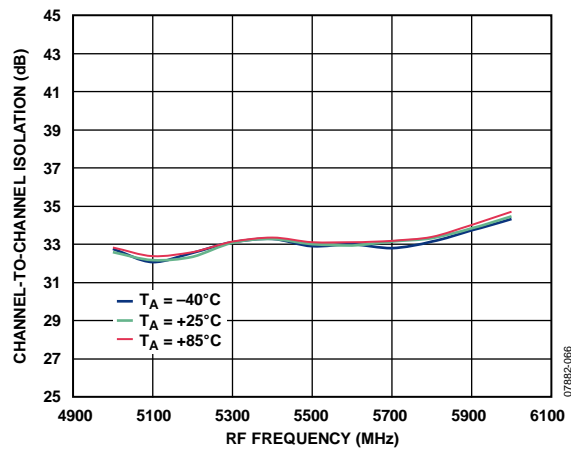


Figure 66. Channel-to-Channel Isolation

**SPUR PERFORMANCE**

All spur tables are  $(N \times f_{RF}) - (M \times f_{LO})$  and were measured using the standard evaluation board (see the Evaluation Board section). Mixer spurious products are measured in decibels relative to the carrier (dBc) from the IF output power level. Data was measured for frequencies less than 6 GHz only. The typical noise floor of the measurement system is  $-100$  dBm.

**900 MHz Performance**

$V_S = 5$  V,  $V_{SET} = 4$  V,  $T_A = 25^\circ\text{C}$ , RF power = 0 dBm, LO power = 0 dBm,  $f_{RF} = 900$  MHz,  $f_{LO} = 703$  MHz,  $Z_0 = 50$   $\Omega$ .

		M															
		0	1	2	3	4	5	6	7	8	9	10	11	12	13	14	
N	0		-35.9	-25.5	-47.3	-27.4	-51.5	-37.5	-62.1	-47.5							
	1	-34.3	0.0	-46.3	-19.8	-64.3	-30.0	-75.6	-45.0	-67.8	-55.3						
	2	-49.1	-69.2	-68.2	-61.6	-68.7	-80.7	-67.5	-88.1	-79.1	-82.6	-91.5	≤-100				
	3	-86.7	-79.6	≤-100	-67.3	-98.0	-71.0	≤-100	-86.3	≤-100	≤-100	≤-100	≤-100	-98.4	≤-100		
	4	-91.8	≤-100	-96.4	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	
	5	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	6	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	7		≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	8			≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	9				≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	10						≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	11							≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	12								≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	13										≤-100	≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
	14											≤-100	≤-100	≤-100	≤-100	≤-100	≤-100
15													≤-100	≤-100	≤-100	≤-100	

**2090 MHz Performance**

$V_S = 5$  V,  $V_{SET} = 4$  V,  $T_A = 25^\circ\text{C}$ , RF power = 0 dBm, LO power = 0 dBm,  $f_{RF} = 2090$  MHz,  $f_{LO} = 1842$  MHz,  $Z_0 = 50$   $\Omega$ .

		M														
		0	1	2	3	4	5	6	7	8	9	10	11	12	13	14
N	0		−43.0	−23.7	−52.9											
	1	−26.8	0.0	−59.6	−42.2	−80.5										
	2	−59.8	−71.9	−53.8	−67.5	−68.2	−84.1									
	3		−67.6	−97.6	−59.3	−92.2	−79.3	≤−100								
	4			≤−100	≤−100	−93.7	−97.8	≤−100	≤−100							
	5				≤−100	≤−100	−96.1	≤−100	≤−100	≤−100						
	6					≤−100	≤−100	≤−100	≤−100	≤−100	≤−100					
	7						≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	≤−100			
	8							≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	≤−100		
	9								≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	
	10										≤−100	≤−100	≤−100	≤−100	≤−100	≤−100
	11											≤−100	≤−100	≤−100	≤−100	≤−100
	12													≤−100	≤−100	≤−100
	13														≤−100	≤−100
	14															≤−100
	15															

**2600 MHz Performance**

$V_S = 5\text{ V}$ ,  $V_{SET} = 4.5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , RF power = 0 dBm, LO power = 0 dBm,  $f_{RF} = 2600\text{ MHz}$ ,  $f_{LO} = 2350\text{ MHz}$ ,  $Z_0 = 50\ \Omega$ .

		M														
		0	1	2	3	4	5	6	7	8	9	10	11	12	13	14
N	0		−37.9	−31.5												
	1	−27.5	0.0	−62.6	−36.3											
	2	−75.5	−59.7	−52.2	−65.8	−68.8										
	3		−75.0	−88.7	−56.3	−86.8	−90.5									
	4			≤−100	≤−100	−82.5	−92.1	≤−100								
	5				≤−100	≤−100	−94.4	≤−100	≤−100	≤−100						
	6						≤−100	≤−100	≤−100	≤−100	≤−100					
	7							≤−100	≤−100	≤−100	≤−100	≤−100				
	8								≤−100	≤−100	≤−100	≤−100	≤−100			
	9									≤−100	≤−100	≤−100	≤−100	≤−100		
	10										≤−100	≤−100	≤−100	≤−100	≤−100	
	11											≤−100	≤−100	≤−100	≤−100	≤−100
	12												≤−100	≤−100	≤−100	≤−100
	13													≤−100	≤−100	≤−100
	14														≤−100	≤−100
15																

**3500 MHz Performance**

$V_S = 5\text{ V}$ ,  $V_{SET} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , RF power = 0 dBm, LO power = 0 dBm,  $f_{RF} = 3500\text{ MHz}$ ,  $f_{LO} = 3800\text{ MHz}$ ,  $Z_0 = 50\ \Omega$ .

		M														
		0	1	2	3	4	5	6	7	8	9	10	11	12	13	14
N	0		−43.0	−23.7	−52.9											
	1	−26.8	0.0	−59.6	−42.2	−80.5										
	2	−59.8	−71.9	−53.8	−67.5	−68.2	−84.1									
	3		−67.6	−97.6	−59.3	−92.2	−79.3	≤−100								
	4			≤−100	≤−100	−93.7	−97.8	≤−100	≤−100							
	5				≤−100	≤−100	−96.1	≤−100	≤−100	≤−100						
	6					≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	≤−100				
	7						≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	≤−100			
	8							≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	≤−100		
	9								≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	≤−100	
	10										≤−100	≤−100	≤−100	≤−100	≤−100	≤−100
	11											≤−100	≤−100	≤−100	≤−100	≤−100
	12												≤−100	≤−100	≤−100	≤−100
	13													≤−100	≤−100	≤−100
	14														≤−100	≤−100
15																≤−100

**5800 MHz Performance**

$V_S = 5\text{ V}$ ,  $V_{SET} = 4.8\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , RF power =  $-10\text{ dBm}$ , LO power =  $0\text{ dBm}$ ,  $f_{RF} = 5800\text{ MHz}$ ,  $f_{LO} = 5600\text{ MHz}$ ,  $Z_0 = 50\ \Omega$ .

		M														
		0	1	2	3	4	5	6	7	8	9	10	11	12	13	14
N	0		−28.3													
	1	−63.6	0.0	−80.5												
	2			−48.6	−92.6											
	3				−64.2	−98.7										
	4					−90.5	−98.3									
	5						≤−100	−99.4								
	6							−81.6	−98.0							
	7								−87.2	−95.9						
	8									−84.0	−99.5					
	9										≤−100	≤−100				
	10											≤−100	≤−100			
	11												≤−100	≤−100		
	12													≤−100	−99.6	
	13														≤−100	−99.8
	14															≤−100
	15															

## CIRCUIT DESCRIPTION

The **ADL5802** provides two double-balanced active mixers. These mixers are designed for a 50  $\Omega$  input impedance and a 200  $\Omega$  output impedance. Both are driven from a common local oscillator (LO) amplifier. The RF inputs and LO outputs are differential, providing maximum usable bandwidth at the input and output ports. The LO also operates with a 50  $\Omega$  input impedance and can, optionally, be operated differentially or single-ended. The input, output, and LO ports can be operated over an exceptionally wide frequency range. The **ADL5802** can be configured as a downconvert mixer or as an upconvert mixer.

The **ADL5802** can be divided into the following sections: the local oscillator (LO) amplifier and splitter, the RF voltage-to-current (V-to-I) converter, the mixer cores, the output loads, and the bias circuit. A simplified block diagram of the device is shown in Figure 67. The LO block generates a pair of differential LO signals to drive two mixer cores. The RF input is converted into current by the V-to-I converters that then feed into the two mixer cores. The internal differential load of the mixers is designed for a wideband 200  $\Omega$  output impedance from the mixer. Reference currents to each section are generated by the bias circuit, which can be enabled or disabled using the ENBL pin. A detailed description of each section of the **ADL5802** follows.

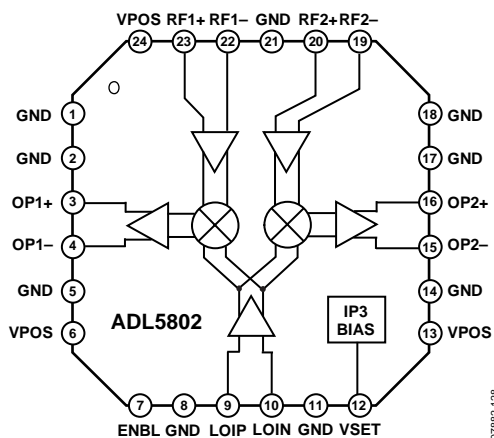


Figure 67. **ADL5802** Block Diagram

### LO AMPLIFIER AND SPLITTER

The LO input is amplified using a broadband LNA and is then split and followed by separate LO limiting amplifiers. The LNA input impedance is nominally 50  $\Omega$ . The LO is designed to accommodate a wide range of LO input power levels. The LO input is conditioned by the series of amplifiers to provide a well controlled and limited LO swing to the mixer core, resulting in excellent IP3. The LO circuit exhibits low additive noise, resulting in an excellent mixer noise figure and output noise under RF blocking. For optimal performance, the LO inputs should be driven differentially but at lower frequencies; single-ended drive is acceptable.

### RF VOLTAGE TO CURRENT (V-TO-I) CONVERTER

The differential RF input signal is applied to a voltage-to-current converter that converts the differential input voltage to output currents. The V-to-I converter provides a 50  $\Omega$  input impedance. The V-to-I section bias current can be adjusted up or down using the VSET pin. Adjusting the current up improves IP3 and P1dB input but degrades SSB NF. Adjusting the current down improves SSB NF but degrades IP3 and P1dB input. The conversion gain remains nearly constant over a wide range of VSET pin settings, allowing the part to be adjusted dynamically without affecting the conversion gain. The current adjustment can be made by connecting a resistor from the VSET pin to the positive supply to increase the bias current or from the VSET pin to ground to decrease the bias current. The VSET pin impedance is approximately 675  $\Omega$  in series with two diodes and an internal current source.

### MIXER CORES

The **ADL5802** has two double-balanced mixers that use high performance SiGe NPN transistors. These mixers are based on the Gilbert cell design of four cross-connected transistors.

### MIXER LOAD

Each mixer load is designed to use a pair of 100  $\Omega$  resistors connected to the positive supply. This provides a 200  $\Omega$  differential output resistance. The mixer output should be pulled to the positive supply externally using a pair of RF chokes or using an output transformer with the center tap connected to the positive supply. It is possible to exclude these components when the mixer core current is low, but both P1dB and IP3 are then reduced.

The mixer load output can operate from direct current (dc) up to approximately 500 MHz into a 200  $\Omega$  load. For upconversion applications, the mixer load can be matched using off-chip matching components. Transmit operation up to 2 GHz is possible. See the Applications Information section for matching circuit details.

### BIAS CIRCUIT

A band gap reference circuit generates the reference currents used by the mixers. The bias circuit can be enabled and disabled using the ENBL pin. If the ENBL pin is grounded or left open, the part is enabled. Pulling the ENBL pin high shuts off the bias circuit and disables the part. However, the ENBL pin does not alter the current in the LO section and, therefore, does not provide a true power-down feature. Certain configurations may require the VSET pin to be connected to the positive supply through a resistor. This will result in an increased mixer core current. Unless this resistor to positive supply is removed, bias current will continue to be supplied to the mixer core.

## APPLICATIONS INFORMATION

### BASIC CONNECTIONS

The ADL5802 features dual channel mixers with a common local oscillator (LO). The mixer is designed to translate between radio frequencies (RF) and intermediate frequencies (IF). For both upconversion and downconversion applications, RF1+ (Pin 23), RF1- (Pin 22), RF2+ (Pin 20), and RF2- (Pin 19) must be configured as the input interfaces. OP1+ (Pin 3), OP1- (Pin 4), OP2+ (Pin 16), and OP2- (Pin 15) must be configured as the output interfaces. Figure 68 illustrates the basic connections for ADL5802 operation.

### RF AND LO PORTS

The RF and LO input ports are designed for differential input impedance of approximately 50  $\Omega$ . Figure 69 and Figure 70 illustrate the RF and LO interfaces, respectively. It is recommended that each of the RF and LO differential ports be driven through a balun for optimum performance. It is also necessary to ac-couple both RF and LO ports with the proper size capacitors. Table 4 lists the recommended components for various RF frequency bands. The characterization data is available in the Typical Performance Characteristics section.

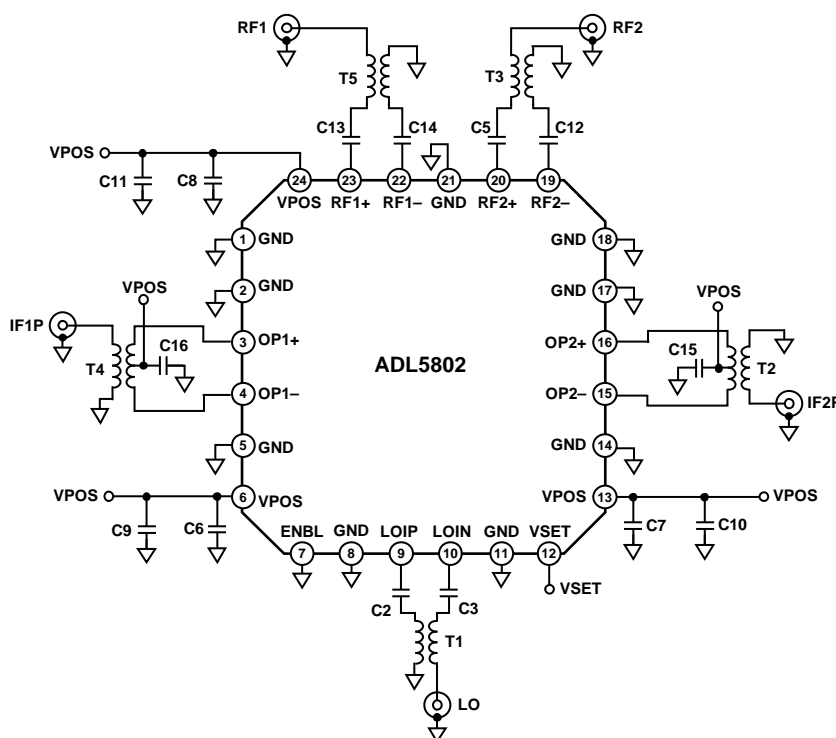


Figure 68. Basic Connections Schematic

07882-101



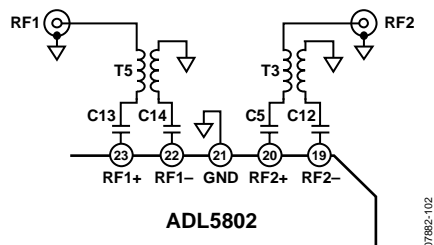


Figure 69. ADL5802 RF Interface

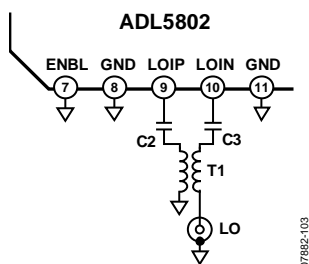


Figure 70. ADL5802 LO Interface

Table 4. Suggested Components for the RF and LO Interfaces

RF and LO Frequency	T1, T3, T5	C2, C3, C5, C12, C13, C14
900 MHz	Mini-Circuits® TC1-1-13M+	100 pF
1900 MHz	Mini-Circuits TC1-1-13M+	100 pF
2500 MHz	Johanson Technology 2500BL14M050	3 pF
3500 MHz	Johanson Technology 3600BL14M050	1.5 pF
5500 MHz	Johanson Technology 5400BL15B050	3 pF

## IF PORT

The IF port features an open-collector differential output interface. It is necessary to bias the open collector outputs using one of the schemes presented in Figure 71 and Figure 72.

Figure 71 shows the use of center-tapped impedance transformers. The turns ratio of the transformer should be selected to provide the desired impedance transformation. In the case of a 50  $\Omega$  load impedance, a 4:1 impedance ratio transformer should be used to transform the 50  $\Omega$  load into a 200  $\Omega$  differential load at the IF output pins.

Figure 72 shows a differential IF interface where pull-up choke inductors are used to bias the open-collector outputs. The shunting impedance of the choke inductors used to couple dc current into the mixer core should be large enough at the IF frequency of operation so as not to load down the output current before it reaches the intended load. Additionally, the dc current handling capability of the selected choke inductors must be at least 45 mA. The self-resonant frequency of the selected choke inductors must be higher than the intended IF

frequency. A variety of suitable choke inductors is commercially available from manufacturers such as Coilcraft and Murata. An impedance transforming network may be required to transform the final load impedance to 200  $\Omega$  at the IF outputs.

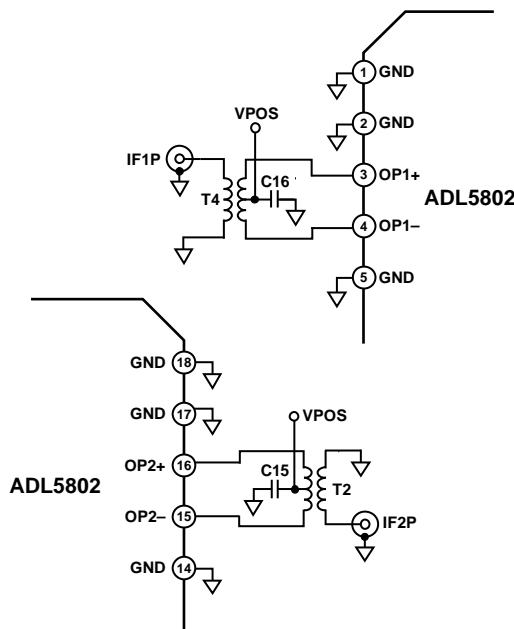


Figure 71. Biasing the IF Port Open-Collector Outputs Using a Center-Tapped Impedance Transformer

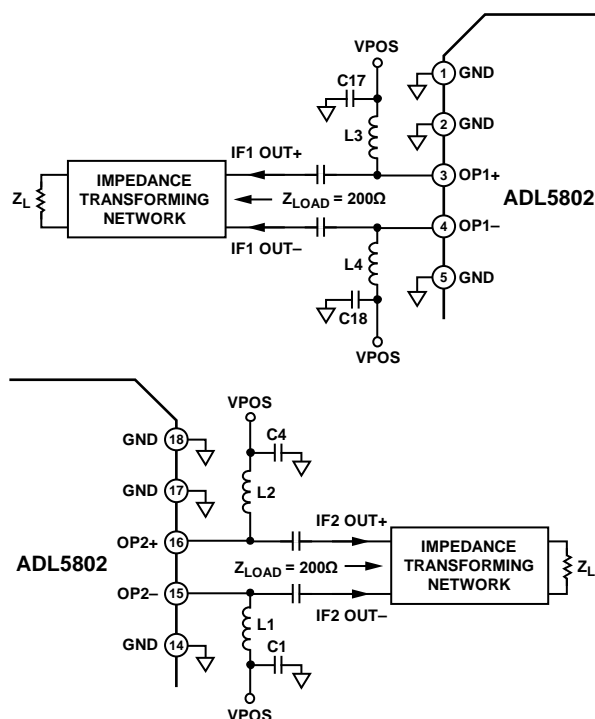


Figure 72. Biasing the IF Port Open-Collector Outputs Using Pull-Up Choke Inductors

**PERFORMANCE UP TO 8 GHz**

This section provides the typical performance of the [ADL5802](#) from 6 GHz to 8 GHz. The output trace and connector loss are not deembedded for these measurements.

$V_S = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $IF = 200\text{ MHz}$ , as measured using a typical circuit schematic with a low-side local oscillator (LO), unless otherwise noted. LO and RF ports use TCM1-83X+, IF ports use TC1-1-13M+. Insertion loss of input and output balun, and traces loss are not extracted from the gain measurement.

Note that this performance is typical and is not guaranteed.

**Table 5.**

Parameter	Test Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE AT $f_{RF}$ BETWEEN 6 GHz AND 8 GHz	$V_{SET} = 2.5\text{ V}$				
Power Conversion Gain			−6		dB
SSB Noise Figure			19		dB
Input Third-Order Intercept			15		dBm

## EVALUATION BOARD

An evaluation board is available for the [ADL5802](#). The standard evaluation board is fabricated using Rogers® RO3003 material. Each of the RF, LO, and IF ports is configured for single-ended signaling via a balun transformer. The schematic for the evaluation board is shown in Figure 73. Table 6 describes the various configuration options for the evaluation board. Layout for the board is shown in Figure 74 and Figure 75.

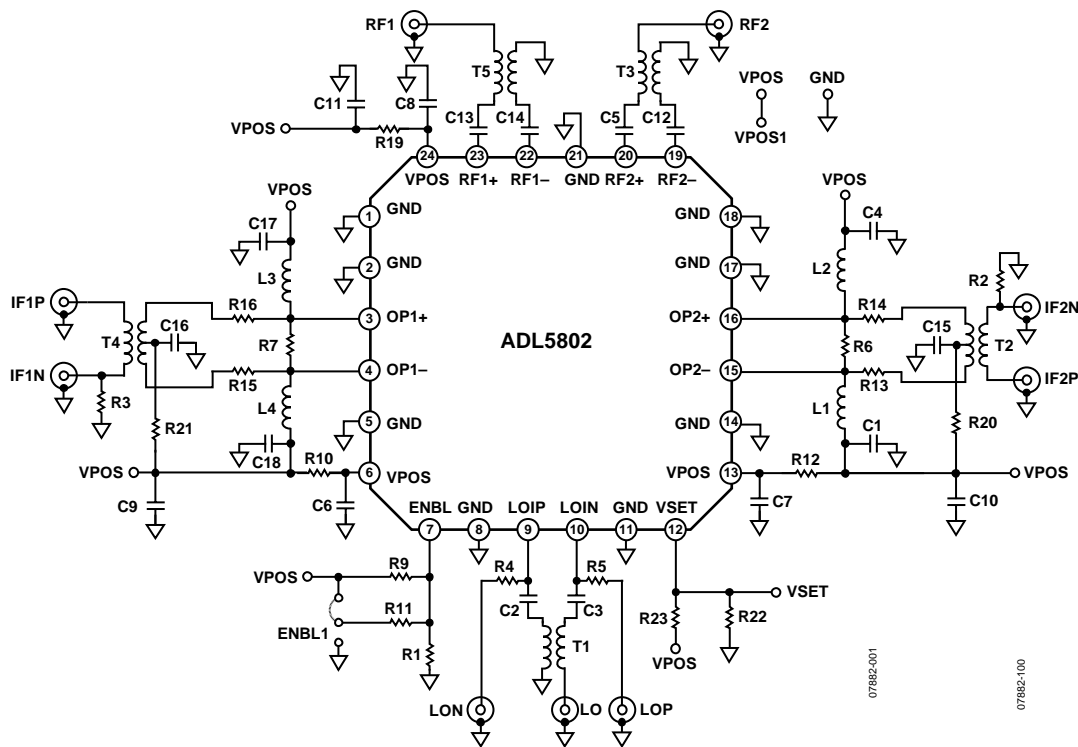


Figure 73. Evaluation Board Schematic

Table 6. Evaluation Board Configuration

Components	Function	Default Conditions
C1, C4, C6, C7, C8, C9, C10, C11, C17, C18, R10, R12, R19, R20, R21	Power supply decoupling. Nominal supply decoupling consists of a 0.01 $\mu$ F capacitor to ground in parallel with 10 pF capacitors to ground, positioned as close to the device as possible. Series resistors are provided for enhanced supply decoupling using optional ferrite chip inductors.	C6, C7, C8 = 10 pF (size 0402) C9, C10, C11 = 0.01 $\mu$ F (size 0402) C1, C4, C17, C18 = open (size 0402) R10, R12, R19, R20, R21 = 0 $\Omega$ (size 0402)
C5, C12, C13, C14, T3, T5, RF1, RF2	RF Channel 1 and RF Channel 2 input interfaces. Input channels are ac-coupled through C5, C12, C13, and C14. T3 and T4 are 1:1 baluns used to interface to the 50 $\Omega$ differential inputs.	C5, C12, C13, C14 = 100 pF (size 0402) T3, T5 = TC1-1-13M+ (Mini-Circuits)
C15, C16, L1, L2, L3, L4, R2, R3, R6, R7, R13, R14, R15, R16, R20, R21, T2, T4, IF1, IF2	IF Channel 1 and IF Channel 2 output interfaces. The 200 $\Omega$ open-collector IF output interfaces are biased through the center taps of T2 and T4 4:1 impedance transformers. C15 and C16 provide local bypassing with R20 and R21 available for additional supply bypassing. R6, R7, R13, R14, R15, and R16 are provided for IF filtering and matching options.	C15, C16 = 100 pF (size 0402) L1, L2, L3, L4 = open (size 0805) R2, R3, R13, R14, R15, R16, R20, R21 = 0 $\Omega$ (size 0402) R6, R7 = open (size 0402) T2, T4 = TC4-1W+ (Mini-Circuits)
C2, C3, R4, R5, T1, LO	LO interface. C2 and C3 provide ac coupling for the local oscillator input. T1 is a 1:1 balun to allow single-ended interfacing to the differential 50 $\Omega$ local oscillator input.	C2, C3 = 1 nF (size 0402) R4, R5 = open (size 0402) T1 = TC1-1-13M+ (Mini-Circuits)
R1, R9, R11, ENBL1	Enable interface. The <a href="#">ADL5802</a> can be disabled using the 3-pin ENBL1 header. The ENBL pin is pulled up to VPOS through R9. R1 is provided as an optional termination for the high impedance enable interface. If desired, the ENBL pin can be driven by an external source through the ENBL SMA connector.	R9 = 10 k $\Omega$ (size 0402); R1, R11 = open (size 0402) Or R1 = 10 k $\Omega$ (size 0402); R9, R11 = open (size 0402) Or R11 = 10 k $\Omega$ (size 0402); R1, R9 = open (size 0402) ENBL1 = 3-pin header and shunt

Components	Function	Default Conditions
R22, R23, VSET	VSET bias control. R22 and R23 form an optional resistor divider network between VPOS and GND, allowing for a fixed bias setting. See the Typical Performance Characteristics section to choose the recommended VSET control voltage for the desired frequency band.	R22, R23 = open (size 0402)
EPAD (EP)	Exposed paddle. Must be soldered to ground.	

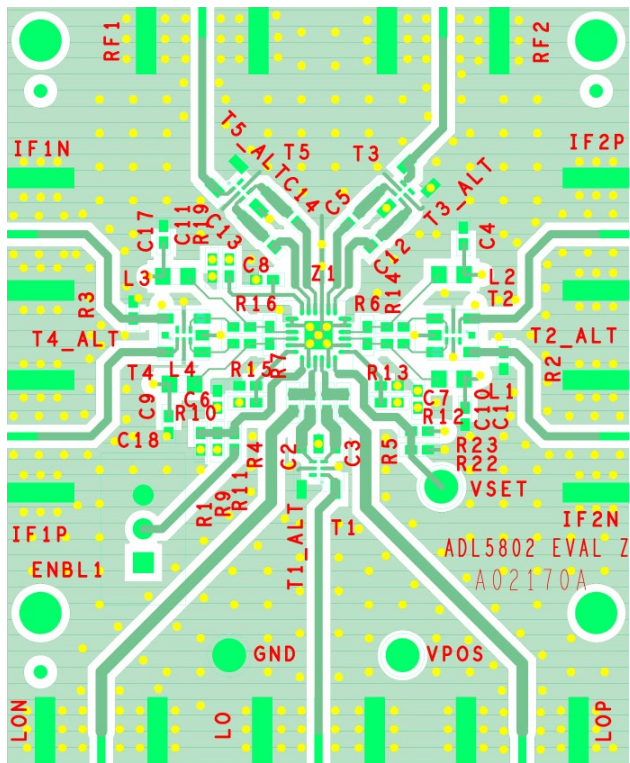


Figure 74. Evaluation Board Top Layer

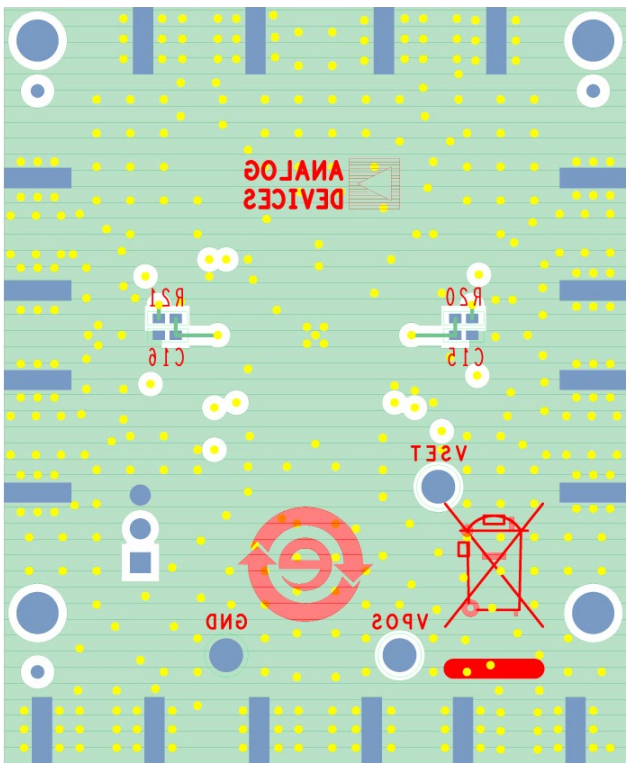
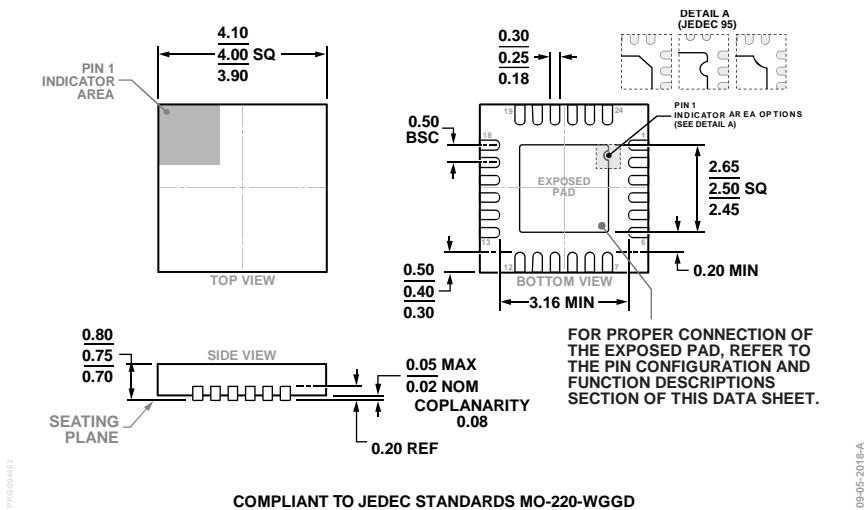


Figure 75. Evaluation Board Bottom Layer

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-WGGD

Figure 76. 24-Lead Lead Frame Chip Scale Package [LFCSP]  
4 mm × 4 mm Body and 0.75 mm Package Height  
(CP-24-7)  
Dimensions shown in millimeters

ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Ordering Quantity
ADL5802ACPZ-R7	−40°C to +85°C	24-Lead Lead Frame Chip Scale Package [LFCSP]	CP-24-7	1,500 per Reel
ADL5802-EVALZ		Evaluation Board		1

<sup>1</sup> Z = RoHS Compliant Part.

## NOTES

**NOTES**

## NOTES